



SamHop Microelectronics Corp.



SP6719

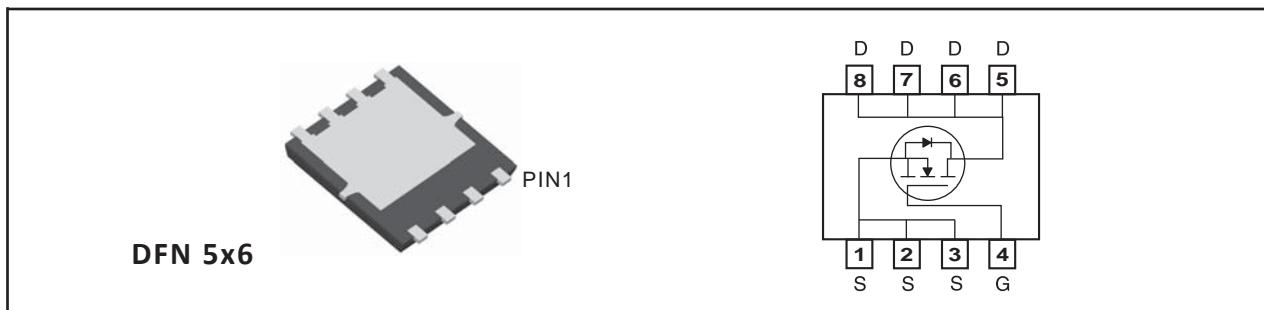
Ver 1.0

N-Channel Logic Level Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (mΩ) Max
60V	11A	12.5 @ VGS=10V
		19.0 @ VGS=4.5V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter		Limit	Units
V_{DS}	Drain-Source Voltage		60	V
V_{GS}	Gate-Source Voltage		± 20	V
I_D	Drain Current-Continuous ^c	$T_A=25^\circ\text{C}$	11	A
		$T_A=70^\circ\text{C}$	8.8	A
I_{DM}	-Pulsed ^{a c}		39	A
E_{AS}	Single Pulse Avalanche Energy ^d		256	mJ
P_D	Maximum Power Dissipation	$T_A=25^\circ\text{C}$	3.1	W
		$T_A=70^\circ\text{C}$	2	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range		-55 to 150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	40	$^\circ\text{C/W}$
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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BVDSS	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	60			V
IDS _S	Zero Gate Voltage Drain Current	$V_{DS}=48V, V_{GS}=0V$			1	μA
IGSS	Gate-Body Leakage Current	$V_{GS} = \pm 20V, V_{DS}=0V$			± 100	nA
ON CHARACTERISTICS						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1	2	3	V
R _{DSON}	Drain-Source On-State Resistance	$V_{GS}=10V, I_D=5.5A$		10	12.5	m ohm
		$V_{GS}=4.5V, I_D=4.5A$		14	19.0	m ohm
g _{FS}	Forward Transconductance	$V_{DS}=10V, I_D=5.5A$		22		S
DYNAMIC CHARACTERISTICS ^b						
C _{ISS}	Input Capacitance	$V_{DS}=25V, V_{GS}=0V$ $f=1.0MHz$		2525		pF
C _{OSS}	Output Capacitance			236		pF
C _{RSS}	Reverse Transfer Capacitance			195		pF
SWITCHING CHARACTERISTICS ^b						
t _{D(ON)}	Turn-On Delay Time	$V_{DD}=30V$ $I_D=1A$ $V_{GS}=10V$ $R_{GEN}=6\text{ ohm}$		49		ns
t _r	Rise Time			63		ns
t _{D(OFF)}	Turn-Off Delay Time			122		ns
t _f	Fall Time			25		ns
Q _g	Total Gate Charge	$V_{DS}=30V, I_D=5.5A, V_{GS}=10V$		39		nC
		$V_{DS}=30V, I_D=5.5A, V_{GS}=4.5V$		20		nC
Q _{gs}	Gate-Source Charge	$V_{DS}=30V, I_D=5.5A,$ $V_{GS}=10V$		4		nC
Q _{gd}	Gate-Drain Charge			11		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=2A$		0.75	1.3	V
Notes						
a.Pulse Test:Pulse Width < 10us, Duty Cycle < 1%.						
b.Guaranteed by design, not subject to production testing.						
c.Drain current limited by maximum junction temperature.						
d.Starting $T_J=25^\circ C, L=0.5mH, V_{DD} = 30V$. (See Figure13)						
e.Mounted on FR4 Board of 1 inch ² , 2oz.						

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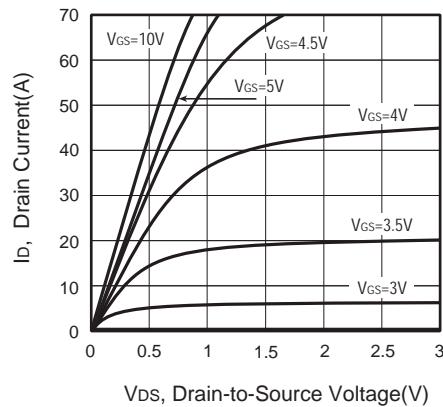


Figure 1. Output Characteristics

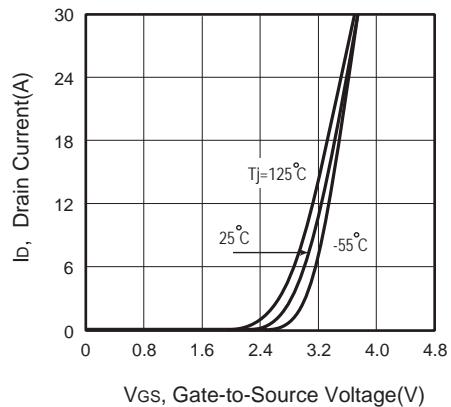


Figure 2. Transfer Characteristics

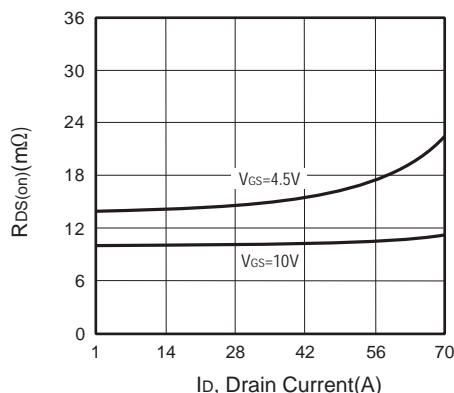


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

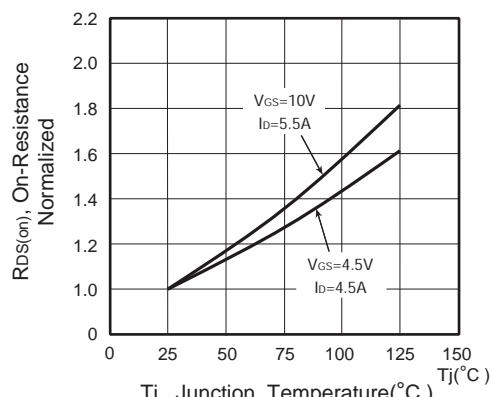


Figure 4. On-Resistance Variation with Drain Current and Temperature

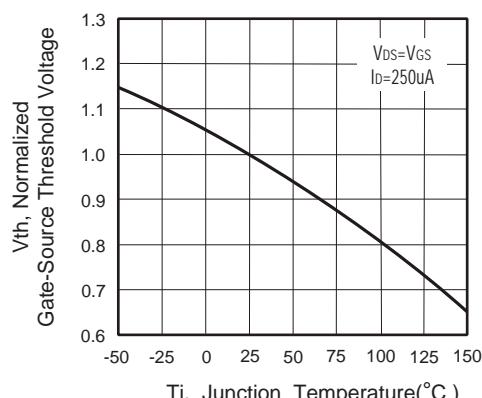


Figure 5. Gate Threshold Variation with Temperature

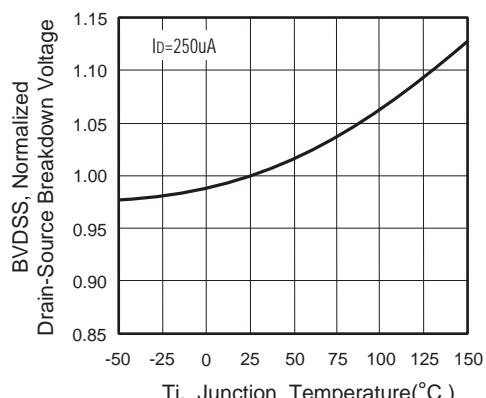


Figure 6. Breakdown Voltage Variation with Temperature

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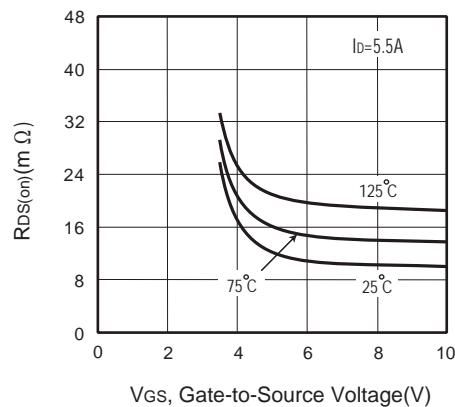


Figure 7. On-Resistance vs. Gate-Source Voltage

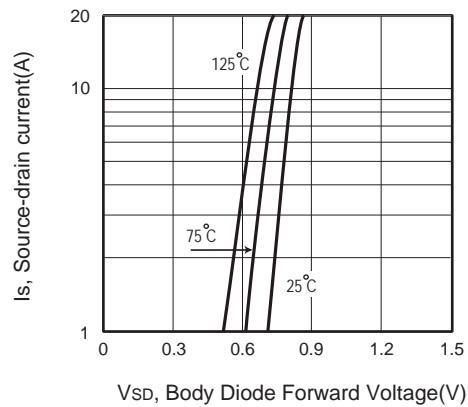


Figure 8. Body Diode Forward Voltage Variation with Source Current

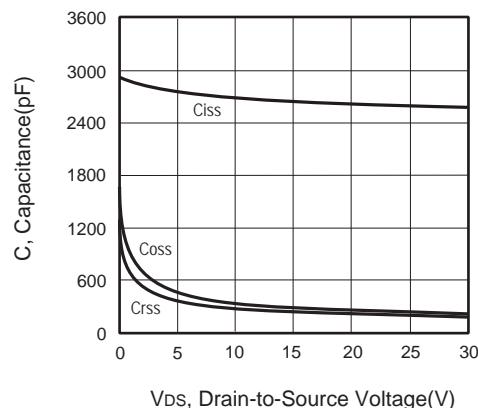


Figure 9. Capacitance

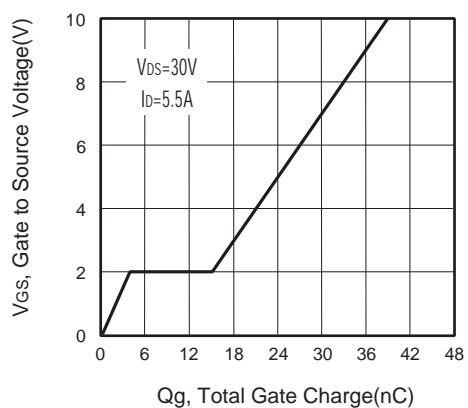


Figure 10. Gate Charge

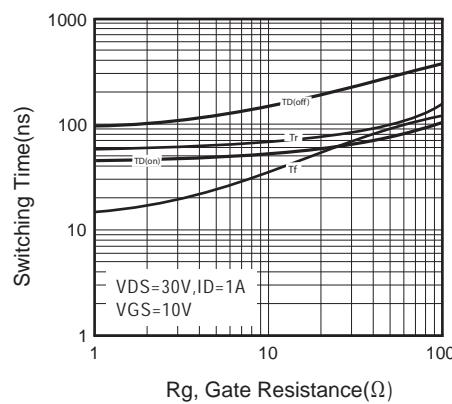


Figure 11. switching characteristics

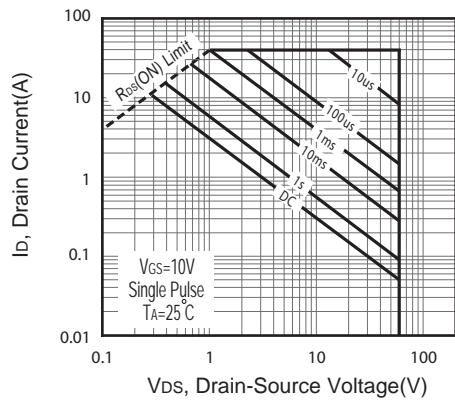
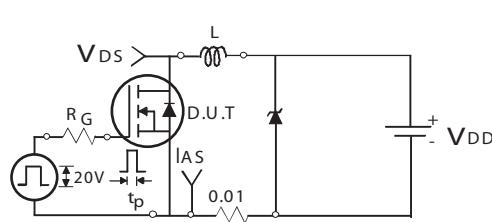


Figure 12. Maximum Safe Operating Area

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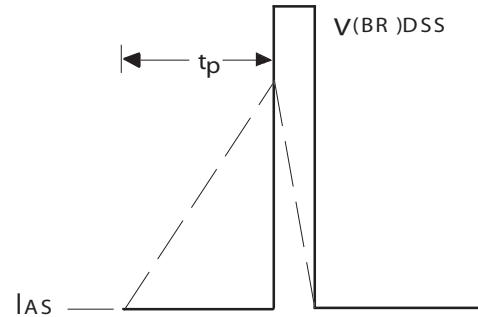
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Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

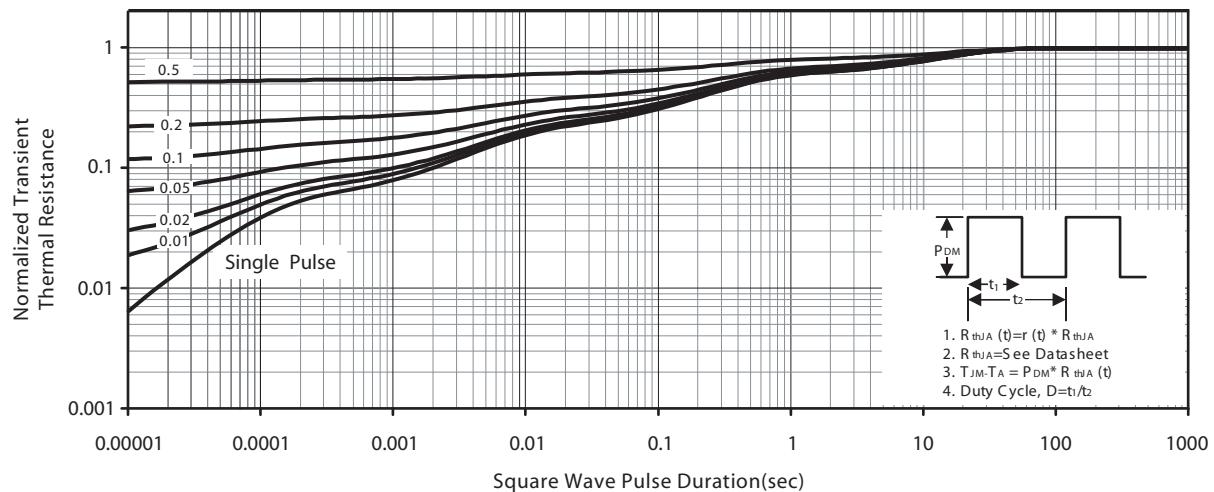
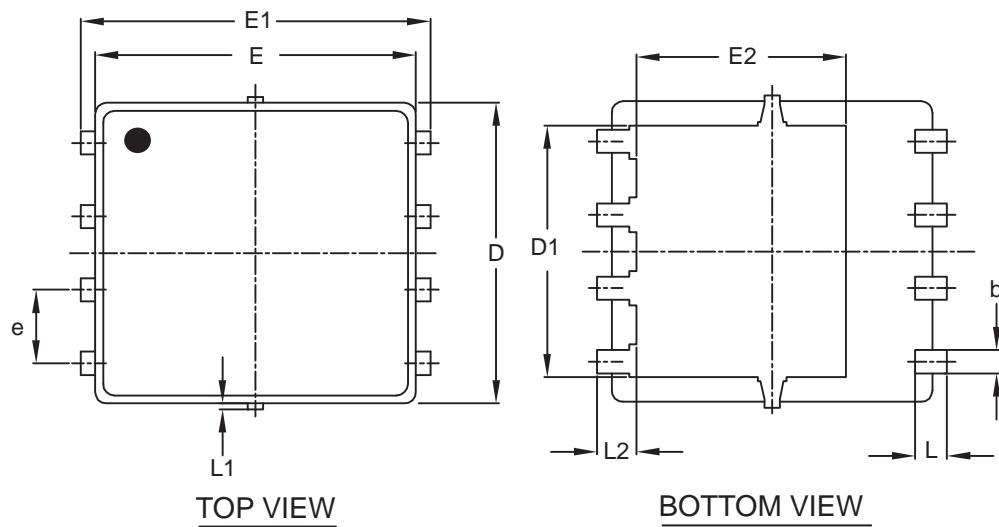


Figure 13. Normalized Thermal Transient Impedance Curve

PACKAGE OUTLINE DIMENSIONS

DFN 5x6-8L



SYMBOLS	MILLIMETERS		
	MIN	NOM	MAX
A	0.85	0.95	1.00
A1	0.00	—	0.05
b	0.30	0.40	0.50
c	0.15	0.20	0.25
D	5.20 BSC		
D1	4.35 BSC		
E	5.55 BSC		
E1	6.05 BSC		
E2	3.62 BSC		
e	1.27 BSC		
L	0.45	0.55	0.65
L1	0.00	—	0.15
L2	0.68 REF		
θ	0°	—	10°

TOP MARKING DEFINITION

DFN 5x6-8L

